

# FDW254P

## P-Channel 1.8V Specified PowerTrench® MOSFET

## **General Description**

This P-Channel 1.8V specified MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (1.8V-8V).

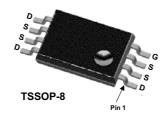
## **Applications**

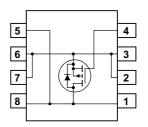
- Load switch
- · Motor drive
- DC/DC conversion
- Power management

## **Features**

 $\begin{array}{ll} \bullet & -9.2 \text{ A, } -20 \text{ V.} & R_{DS(ON)} = 12 \text{ m}\Omega \text{ @ V}_{GS} = -4.5 \text{ V} \\ & R_{DS(ON)} = 15 \text{ m}\Omega \text{ @ V}_{GS} = -2.5 \text{ V} \\ & R_{DS(ON)} = 21.5 \text{ m}\Omega \text{ @ V}_{GS} = -1.8 \text{ V} \end{array}$ 

- Rds ratings for use with 1.8 V logic
- · Low gate charge
- High performance trench technology for extremely low  $R_{\mbox{\scriptsize DS(ON)}}$
- Low profile TSSOP-8 package





## Absolute Maximum Ratings T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V <sub>DSS</sub>	Drain-Source Voltage	-20	V	
V <sub>GSS</sub>	Gate-Source Voltage	±8	V	
I <sub>D</sub>	Drain Current - Continuous (Note	-9.2	A	
	– Pulsed	-50		
P <sub>D</sub>	Power Dissipation (Note	1a) 1.3	W	
	(Note	1b) 0.6		
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Ran	ge —55 to +150	°C	

## **Thermal Characteristics**

R <sub>θJA</sub>	Thermal Resistance, Junction-to-Ambient	(Note 1a)	96	°C/W
		(Note 1b)	208	

**Package Marking and Ordering Information** 

Device Marking	Device	Reel Size	Tape width	Quantity
254P	FDW254P	13"	12mm	2500 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics			I	I	I
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-20			V
ΔBV <sub>DSS</sub> ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D$ = -250 $\mu$ A, Referenced to 25°C		-11		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = -16 \text{ V},  V_{GS} = 0 \text{ V}$			-1	μΑ
I <sub>GSSF</sub>	Gate-Body Leakage, Forward	$V_{GS} = -8 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			-100	nA
I <sub>GSSR</sub>	Gate-Body Leakage, Reverse	V <sub>GS</sub> = 8 V V <sub>DS</sub> = 0 V			100	nA
On Char	acteristics (Note 2)		•	,	,	,
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-0.4	-0.6	-1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_{,J}}$	Gate Threshold Voltage Temperature Coefficient	$I_D$ = –250 μA, Referenced to 25°C		2		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$\begin{array}{cccccccccccccccccccccccccccccccccccc$		9 11 14 12	12 15 21.5 18	mΩ
I <sub>D(on)</sub>	On–State Drain Current	$V_{GS} = -4.5 \text{ V}, \qquad V_{DS} = -5 \text{ V}$	-50			Α
g <sub>FS</sub>	Forward Transconductance	$V_{DS} = -5 \text{ V}, \qquad I_{D} = -9.2 \text{ A}$		54		S
Dynamic	Characteristics					
C <sub>iss</sub>	Input Capacitance	$V_{DS} = -10 \text{ V},  V_{GS} = 0 \text{ V},$		5878		pF
Coss	Output Capacitance	f = 1.0 MHz		994		pF
C <sub>rss</sub>	Reverse Transfer Capacitance	7		559		pF
Switchin	ng Characteristics (Note 2)					
t <sub>d(on)</sub>	Turn-On Delay Time	$V_{DD} = -10 \text{ V}, \qquad I_{D} = -1 \text{ A},$		15	27	ns
T <sub>r</sub>	Turn-On Rise Time	$V_{GS} = -4.5 \text{ V},  R_{GEN} = 6 \Omega$		15	27	ns
$T_{d(off)}$	Turn-Off Delay Time	7		210	336	ns
t <sub>f</sub>	Turn-Off Fall Time	7		100	160	ns
Q <sub>g</sub>	Total Gate Charge	$V_{DS} = -10 \text{ V},  I_{D} = -9.2 \text{ A},$		60	96	nC
$\overline{Q_gs}$	Gate–Source Charge	V <sub>GS</sub> = -4.5 V		7		nC
$Q_{gd}$	Gate-Drain Charge	7		13		nC
Drain-S	ource Diode Characteristics	and Maximum Ratings	•	•	•	•
Is	Maximum Continuous Drain–Source	<del>_</del>			-1.2	Α
V <sub>SD</sub>	Drain–Source Diode Forward Voltage	$V_{GS} = 0 \text{ V},  I_S = -1.2 \text{ A}  \text{(Note 2)}$		-0.5	-1.2	V

<sup>1.</sup>  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.

a) R $_{0JA}$  is 96°C/W (steady state) when mounted on a 1 inch² copper pad on FR-4. b) R $_{0JA}$  is 208°C/W (steady state) when mounted on a minimum copper pad on FR-4.

<sup>2.</sup> Pulse Test: Pulse Width < 300 $\mu$ s, Duty Cycle < 2.0%

## **Typical Characteristics**

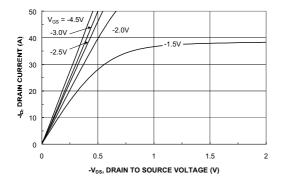


Figure 1. On-Region Characteristics.

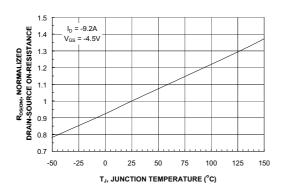


Figure 3. On-Resistance Variation with Temperature.

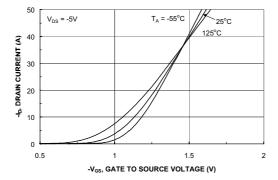


Figure 5. Transfer Characteristics.

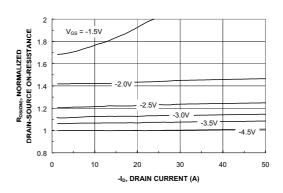


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

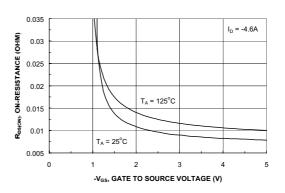


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

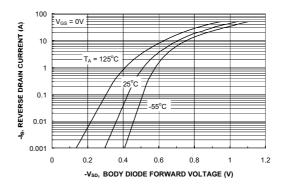
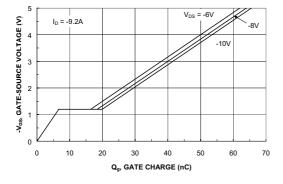


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

# **Typical Characteristics**



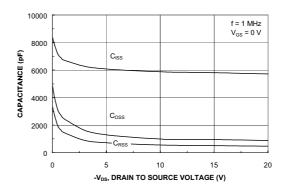
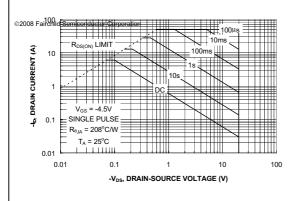


Figure 7. Gate Charge Characteristics.





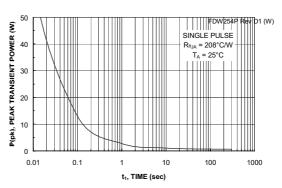


Figure 9. Maximum Safe Operating Area.

Figure 10. Single Pulse Maximum Power Dissipation.

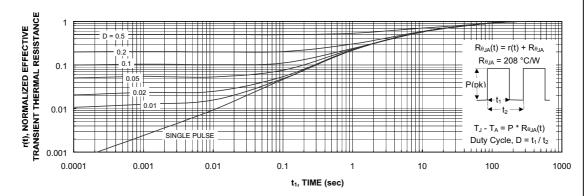


Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1b. Transient thermal response will change depending on the circuit board design.





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